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#### FEMTOCLOCKS™ CRYSTAL-TO-LVCMOS/LVTTL FREQUENCY SYNTHESIZER

## ICS840001-34

## **General Description**

The ICS840001-34 is a two output LVCMOS/LVTTL Synthesizer. One output is the LVCMOS/LVTTL main synthesized clock output (Q) and one output is a three-state LVCMOS/LVTTL reference clock (REF\_OUT) output at the frequency of the crystal oscillator. The device can accept crystals from 15.3125MHz to 42.67MHz and can synthesize outputs from 81.67MHz to 213.33MHz. The ICS840001-34 is packaged in a 3mm x 3mm 16-pin VFQFN, making it ideal for use on space constrained boards..

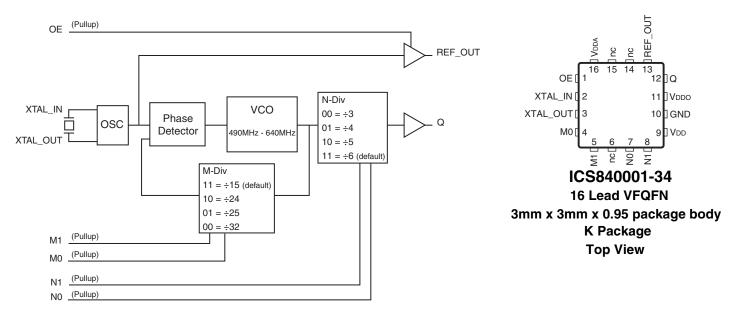
### **Features**

- Two LVCMOS/LVTTL outputs, 22Ω typical output impedance One main clock output (Q) One three-state reference clock output (REF\_OUT)
- Crystal oscillator interface can accept crystals from 15.3125MHz to 42.67MHz, 18pF parallel resonant crystal
- Q output frequency range: 81.67MHz to 213.33MHz
- RMS phase jitter @106.25, (637kHz 10MHz): 0.38ps (typical)
- VCO range: 490MHz to 640MHz
- Full 3.3V and 2.5V operating supply
- 0°C to 70°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

| Inputs        |           |           |           | Output Frequency |                                                         |
|---------------|-----------|-----------|-----------|------------------|---------------------------------------------------------|
| Crystal (MHz) | M Divider | VCO (MHz) | N Divider | (MHz)            | Application                                             |
| 40            | 15        | 600       | 6         | 100 (default)    | Serial Attached (SCSI),<br>PCI Express, Processor Clock |
| 26.5625       | 24        | 637.5     | 6         | 106.25           | Fibre Channel                                           |
| 40            | 15        | 600       | 4         | 150              | Serial ATA (SATA), Processor Clock                      |
| 26.5625       | 24        | 637.5     | 3         | 212.5            | Fibre Channel 2                                         |
| 25            | 25        | 625       | 5         | 125              | Ethernet                                                |
| 25            | 25        | 625       | 4         | 156.25           | 10 Gigabit Ethernet                                     |
| 22.5          | 25        | 562.5     | 3         | 187.5            | 12 Gigabit Ethernet                                     |
| 19.44         | 32        | 622.08    | 4         | 155.52           | SONET                                                   |

# Common Application Configuration Table

## **Block Diagram**



1

**Pin Assignment** 

| Number    | Name                 | Ту     | ре     | Description                                                                                                                                   |
|-----------|----------------------|--------|--------|-----------------------------------------------------------------------------------------------------------------------------------------------|
| 1         | OE                   | Input  | Pullup | Output enable pin. When HIGH, REF_OUT output is enabled. When LOW, forces REF_OUT to Hi-Z state. See Table 3A. LVCMOS/LVTTL interface levels. |
| 2,<br>3   | XTAL_IN,<br>XTAL_OUT | Input  |        | Crystal oscillator interface. XTAL_IN is the input. XTAL_OUT is the output.                                                                   |
| 4, 5      | M0, M1               | Input  | Pullup | M divider inputs. LVCMOS/LVTTL interface levels. See Table 3B.                                                                                |
| 6, 14, 15 | nc                   | Unused |        | No connect.                                                                                                                                   |
| 7, 8      | N0, N1               | Input  | Pullup | Determines output divider value as defined in Table 3C.<br>LVCMOS/LVTTL interface levels.                                                     |
| 9         | V <sub>DD</sub>      | Power  |        | Core supply pin.                                                                                                                              |
| 10        | GND                  | Power  |        | Power supply ground.                                                                                                                          |
| 11        | V <sub>DDO</sub>     | Power  |        | Output supply pin.                                                                                                                            |
| 12        | Q                    | Output |        | Single-ended clock output. $22\Omega$ typical output impedance. LVCMOS/LVTTL interface levels.                                                |
| 13        | REF_OUT              | Output |        | Single-ended three-state reference clock output. 22 $\Omega$ typical output impedance. LVCMOS/LVTTL interface levels.                         |
| 16        | V <sub>DDA</sub>     | Power  |        | Analog supply pin.                                                                                                                            |

## Table 1. Pin Descriptions

NOTE: Pullup refers to intenal input resistors. See Table 2, Pin Characteristics, for typical values.

## **Table 2. Pin Characteristics**

| Symbol              | Parameter                     | Test Conditions                             | Minimum | Typical | Maximum          | Units |
|---------------------|-------------------------------|---------------------------------------------|---------|---------|------------------|-------|
| C <sub>IN</sub>     | Input Capacitance             |                                             |         | 4       |                  | pF    |
| C                   | Power Dissipation Capacitance | V <sub>DD,</sub> V <sub>DDO</sub> = 3.465V  |         | 8       | Maximum<br>30 36 | pF    |
| C <sub>PD</sub>     | Fower Dissipation Capacitance | V <sub>DD,</sub> V <sub>DDO</sub> = 2.625V  |         | 6       |                  | pF    |
| R <sub>PULLUP</sub> | Input Pullup Resistor         |                                             |         | 51      |                  | kΩ    |
| D                   | Quitout Impodance             | V <sub>DD,</sub> V <sub>DDO</sub> = 3.3V±5% | 14      | 22      | 30               | Ω     |
| R <sub>OUT</sub>    | Output Impedance              | V <sub>DD,</sub> V <sub>DDO</sub> = 2.5V±5% | 16      | 26      | 30               | Ω     |

## Table 3A. Control Input Function Table

| Control Input | Output           |
|---------------|------------------|
| OE            | REF_OUT          |
| 0             | Hi-Z             |
| 1             | Active (default) |

## Table 3B. M Divider Function Table

| Contro | I Inputs |                        |
|--------|----------|------------------------|
| M1     | MO       | Feedback Divider Ratio |
| 0      | 0        | ÷32                    |
| 0      | 1        | ÷25                    |
| 1      | 0        | ÷24                    |
| 1      | 1        | ÷15 (default)          |

## Table 3C. N Divider Function Table

| Contro | l Inputs |                      |
|--------|----------|----------------------|
| N1     | NO       | Output Divider Ratio |
| 0      | 0        | ÷3                   |
| 0      | 1        | ÷4                   |
| 1      | 0        | ÷5                   |
| 1      | 1        | ÷6 (default)         |

## **Absolute Maximum Ratings**

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

| Item                                     | Rating                          |
|------------------------------------------|---------------------------------|
| Supply Voltage, V <sub>DD</sub>          | 4.6V                            |
| Inputs, V <sub>I</sub>                   | -0.5V to V <sub>DD</sub> + 0.5V |
| Outputs,V <sub>O</sub>                   | -0.5V to V <sub>DD</sub> + 0.5V |
| Package Thermal Impedance, $\theta_{JA}$ | 76.1°C/W (0 mps)                |
| Storage Temperature, T <sub>STG</sub>    | -65°C to 150°C                  |

## **DC Electrical Characteristics**

#### Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ , $T_A = 0^{\circ}C$ to $70^{\circ}C$

| Symbol           | Parameter               | Test Conditions | Minimum                | Typical | Maximum         | Units |
|------------------|-------------------------|-----------------|------------------------|---------|-----------------|-------|
| V <sub>DD</sub>  | Positive Supply Voltage |                 | 3.135                  | 3.3     | 3.465           | V     |
| V <sub>DDA</sub> | Analog Supply Voltage   |                 | V <sub>DD</sub> – 0.12 | 3.3     | V <sub>DD</sub> | V     |
| V <sub>DDO</sub> | Output Supply Voltage   |                 | 3.135                  | 3.3     | 3.465           | V     |
| I <sub>DD</sub>  | Power Supply Current    |                 |                        |         | 100             | mA    |
| I <sub>DDA</sub> | Analog Supply Current   |                 |                        |         | 12              | mA    |
| I <sub>DDO</sub> | Output Supply Current   |                 |                        |         | 35              | mA    |

#### Table 4B. Power Supply DC Characteristics, V<sub>DD</sub> = V<sub>DDO</sub> = 2.5V $\pm$ 5%, T<sub>A</sub> = 0°C to 70°C

| Symbol           | Parameter               | Test Conditions | Minimum                | Typical | Maximum         | Units |
|------------------|-------------------------|-----------------|------------------------|---------|-----------------|-------|
| V <sub>DD</sub>  | Positive Supply Voltage |                 | 2.375                  | 2.5     | 2.625           | V     |
| V <sub>DDA</sub> | Analog Supply Voltage   |                 | V <sub>DD</sub> – 0.12 | 3.3     | V <sub>DD</sub> | V     |
| V <sub>DDO</sub> | Output Supply Voltage   |                 | 2.375                  | 2.5     | 2.625           | V     |
| I <sub>DD</sub>  | Power Supply Current    |                 |                        |         | 90              | mA    |
| I <sub>DDA</sub> | Analog Supply Current   |                 |                        |         | 12              | mA    |
| I <sub>DDO</sub> | Output Supply Current   |                 |                        |         | 25              | mA    |

| Symbol          | Parameter                   |                       | Test Conditions                                      | Minimum | Typical | Maximum               | Units |
|-----------------|-----------------------------|-----------------------|------------------------------------------------------|---------|---------|-----------------------|-------|
| V               | Input Lligh \               | (altara               | V <sub>DD</sub> = 3.3V                               | 2       |         | V <sub>DD</sub> + 0.3 | V     |
| V <sub>IH</sub> | Input High V                | rollage               | V <sub>DD</sub> = 2.5V                               | 1.7     |         | V <sub>DD</sub> + 0.3 | V     |
| V <sub>IL</sub> |                             | altaga                | V <sub>DD</sub> = 3.3V                               | -0.3    |         | 0.8                   | V     |
|                 | Input Low Voltage           |                       | V <sub>DD</sub> = 2.5V                               | -0.3    |         | 0.7                   | V     |
| I <sub>IH</sub> | Input High<br>Current       | OE, M0, M1,<br>N0, N1 | V <sub>DD</sub> = V <sub>IN</sub> = 3.465V or 2.625V |         |         | 5                     | μA    |
| IIL             | Input Low<br>Current        | OE, M0, M1,<br>N0, N1 | V <sub>DD</sub> = V <sub>IN</sub> = 3.465V or 2.625V | -150    |         |                       | μA    |
| M               | Output High Voltage; NOTE 1 |                       | $V_{DDO} = 3.3V \pm 5\%$                             | 2.6     |         |                       | V     |
| V <sub>OH</sub> |                             | vollage, NOTE T       | V <sub>DDO</sub> = 2.5V±5%                           | 1.8     |         |                       | V     |
| V <sub>OL</sub> | Output Low                  | Voltage; NOTE 1       | V <sub>DDO</sub> = 3.3V±5% or 2.5V±5%                |         |         | 0.5                   | V     |

#### Table 4C. LVCMOS/LVTTL DC Characteristics, V\_{DD} = V\_{DDO} = 3.3V $\pm$ 5% or 2.5V $\pm$ 5%, T\_A = 0°C to 70°CC

NOTE 1: Outputs terminated with 50 $\Omega$  to V<sub>DDO</sub>/2. See Parameter Measurement Information, Output Load Test Circuit diagrams.

#### **Table 5. Crystal Characteristics**

| Parameter                          | Test Conditions | Minimum | Typical     | Maximum | Units |
|------------------------------------|-----------------|---------|-------------|---------|-------|
| Mode of Oscillation                |                 |         | Fundamental |         |       |
| Frequency                          |                 | 15.3125 |             | 42.67   | MHz   |
| Equivalent Series Resistance (ESR) |                 |         |             | 50      | Ω     |
| Shunt Capacitance                  |                 |         |             | 7       | pF    |
| Drive Level                        |                 |         |             | 1       | mW    |

NOTE: It is not recommended to overdrive the crystal input with an external clock.

## **AC Electrical Characteristics**

| Parameter                       | Symbol                    | Test Conditions                                 | Minimum | Typical | Maximum                                                  | Units |
|---------------------------------|---------------------------|-------------------------------------------------|---------|---------|----------------------------------------------------------|-------|
| fout                            | Output Frequency          |                                                 | 81.67   |         | 213.33                                                   | MHz   |
| fiit( <i>Q</i> )                | RMS Phase Jitter, Random; | 100MHz, Integration Range:<br>637kHz – 10MHz    |         | 0.54    | 213.33       0.54       0.38       700       60       52 | ps    |
| <i>t</i> jit(Ø)                 | NOTE 1                    | 106.25MHz, Integration Range:<br>637kHz – 10MHz |         | 0.38    |                                                          | ps    |
| t <sub>R</sub> / t <sub>F</sub> | Output Rise/Fall Time     | 20% to 80%                                      | 200     |         | 700                                                      | ps    |
|                                 |                           | Q, N = 3                                        | 40      |         | 60                                                       | %     |
| odc                             | Output Duty Cycle         | Q, N ≠ 3                                        | 48      |         | 52                                                       | %     |
|                                 |                           | REF_OUT                                         | 48      |         | 52                                                       | %     |

#### Table 6A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ , $T_A = 0^{\circ}C$ to 70°C

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. Device will meet specifications after thermal equilibrium has been reached under these conditions

NOTE 1: Please refer to Phase Noise Plot.

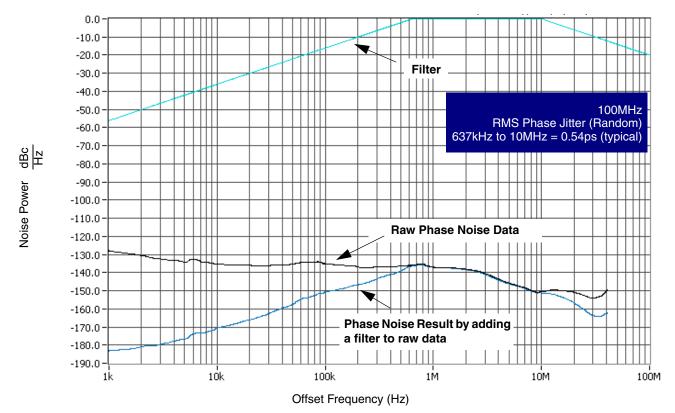
#### Table 6B. AC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$ , $T_A = 0^{\circ}C$ to 70°C

| Parameter                       | Symbol                              | Test Conditions                                 | Minimum | Typical | Maximum | Units |
|---------------------------------|-------------------------------------|-------------------------------------------------|---------|---------|---------|-------|
| fout                            | Output Frequency                    |                                                 | 81.67   |         | 213.33  | MHz   |
| fjit(Ø)                         | RMS Phase Jitter, Random;<br>NOTE 1 | 100MHz, Integration Range:<br>637kHz – 10MHz    |         | 0.54    |         | ps    |
|                                 |                                     | 106.25MHz, Integration Range:<br>637kHz – 10MHz |         | 0.38    |         | ps    |
| t <sub>R</sub> / t <sub>F</sub> | Output Rise/Fall Time               | 20% to 80%                                      | 300     |         | 800     | ps    |
| odc                             | Output Duty Cycle                   | Q, N = 3                                        | 35      |         | 65      | %     |
|                                 |                                     | Q, N ≠ 3                                        | 40      |         | 60      | %     |
|                                 |                                     | REF_OUT                                         | 45      |         | 55      | %     |

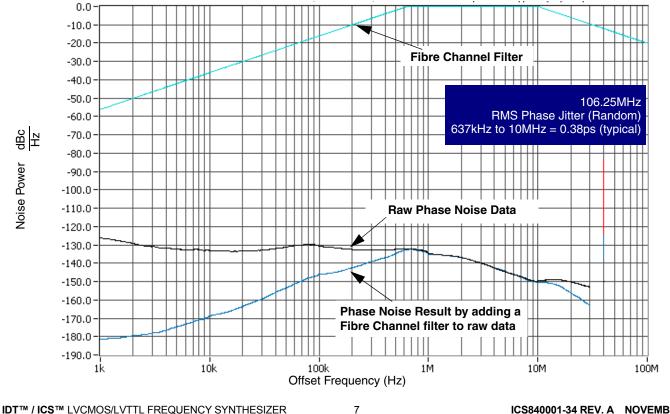
NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. Device will meet specifications after thermal equilibrium has been reached under these conditions

NOTE 1: Please refer to Phase Noise Plot.

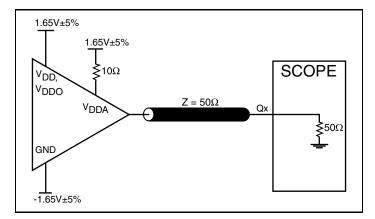
## Typical Phase Noise at 100MHz (3.3V)



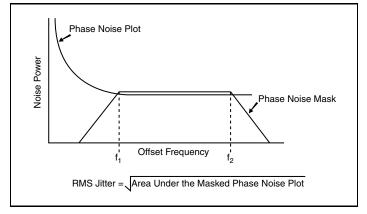
Typical Phase Noise at 106.25MHz (3.3V)



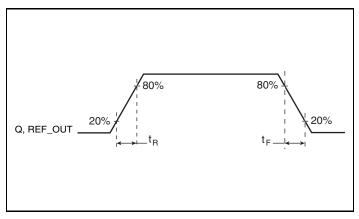
## **Parameter Measurement Information**



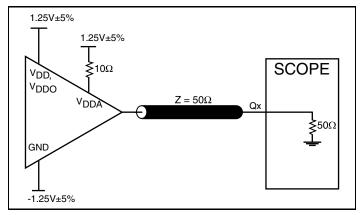
#### 3.3V LVCMOS Output Load AC Test Circuit



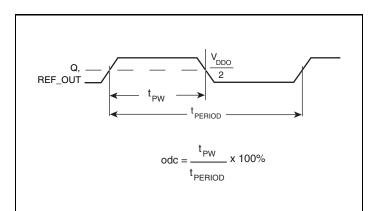
**RMS Phase Jitter** 



**Output Rise/Fall Time** 



#### 2.5V LVCMOS Output Load AC Test Circuit



Output Duty Cycle/Pulse Width/Period

## **Application Information**

#### **Power Supply Filtering Technique**

To achieve optimum jitter performance, power supply isolation is required. The ICS40001I-34 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$ , and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and  $0.01\mu$ F bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic  $V_{DD}$  pin and also shows that  $V_{DDA}$  requires that an additional  $10\Omega$  resistor along with a  $10\mu$ F bypass capacitor be connected to the  $V_{DDA}$  pin.

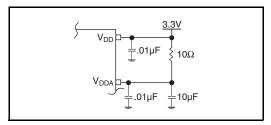


Figure 1. Power Supply Filtering

#### **Recommendations for Unused Input and Output Pins**

#### Inputs:

#### **LVCMOS Control Pins:**

All control pins have internal pull-ups; additional resistance is not required but can be added for additional protection. A 1k $\Omega$  resistor can be used.

#### **Outputs:**

#### LVCMOS Output

All unused LVCMOS output can be left floating. There should be no trace attached.

#### **Crystal Input Interface**

The ICS840001I-34 has been characterized with 18pF parallel resonant crystals. The capacitor values, C1 and C2, shown in *Figure 2* below were determined using a 26.5625MHz, 18pF

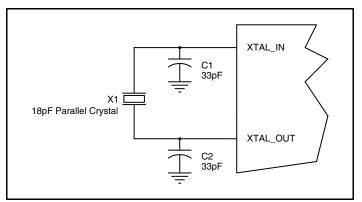


Figure 2. Crystal Input Interface

parallel resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.

#### **VFQFN EPAD Thermal Release Path**

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 4*. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as "heat pipes". The number of vias (i.e. "heat pipes") are

application specific and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor's Thermally/Electrically Enhance Leadframe Base Package, Amkor Technology.

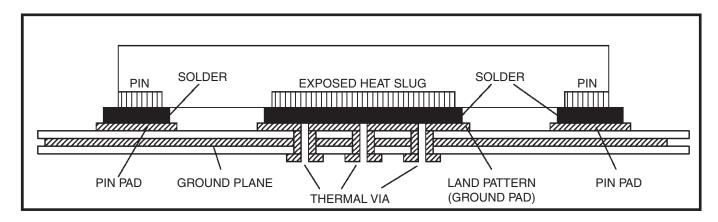


Figure 4. P.C. Assembly for Exposed Pad Thermal Release Path – Side View (drawing not to scale)

## **Reliability Information**

#### Table 7. $\theta_{\text{JA}}$ vs. Air Flow Table for a 16 Lead VFQFN

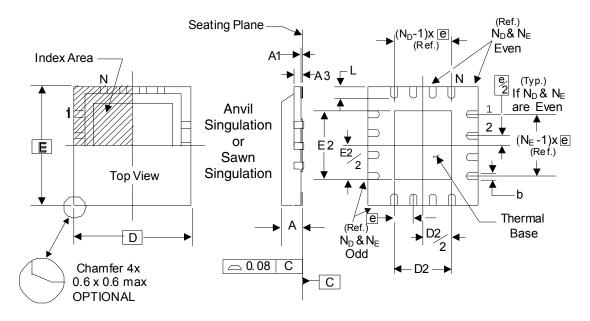
| $\theta_{JA}$ at 0 Air Flow                    |          |      |      |  |
|------------------------------------------------|----------|------|------|--|
| Meters per Second                              | 0 1      |      | 2.5  |  |
| Multi-Layer PCB, JEDEC Standard Test<br>Boards | 76.1°C/W | 66.5 | 59.7 |  |

#### **Transistor Count**

The transistor count for ICS840001-34 is: 2805

## Package Outline and Package Dimensions

Package Outline - K Suffix for 16 Lead VFQFN



#### **Table 8. Package Dimensions**

| JEDEC Variation: VEED-2/-4<br>All Dimensions in Millimeters |            |         |  |  |  |
|-------------------------------------------------------------|------------|---------|--|--|--|
| Symbol                                                      | Minimum    | Maximum |  |  |  |
| N                                                           | 16         |         |  |  |  |
| A                                                           | 0.80       | 1.00    |  |  |  |
| A1                                                          | 0          | 0.05    |  |  |  |
| A3                                                          | 0.25 Ref.  |         |  |  |  |
| b                                                           | 0.18       | 0.30    |  |  |  |
| N <sub>D</sub> & N <sub>E</sub>                             | 4          |         |  |  |  |
| D & E                                                       | 3.00 Basic |         |  |  |  |
| D2 & E2                                                     | 1.00       | 1.80    |  |  |  |
| е                                                           | 0.50 Basic |         |  |  |  |
| L                                                           | 0.30       | 0.50    |  |  |  |

Reference Document: JEDEC Publication 95, MO-220

## **Ordering Information**

#### Table 9. Ordering Information

| Part/Order Number | Marking | Package                   | Shipping Packaging | Temperature |
|-------------------|---------|---------------------------|--------------------|-------------|
| ICS840001AK-34    | 1A34    | 16 Lead VFQFN             | Tray               | 0°C to 70°C |
| ICS840001AK-34T   | 1A34    | 16 Lead VFQFN             | Tape & Reel        | 0°C to 70°C |
| ICS840001AK-34LF  | A34L    | "Lead-Free" 16 Lead VFQFN | Tray               | 0°C to 70°C |
| ICS840001AK-34LFT | A34L    | "Lead-Free" 16 Lead VFQFN | Tape & Reel        | 0°C to 70°C |

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

## **Revision History Sheet**

| Rev | Table     | Page     | Description of Change                                                                                                                                                                | Date    |
|-----|-----------|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------|
| А   |           | 11<br>13 | Updated VFQFN EPAD Thermal Release Path section.<br>Updated Package Drawing.                                                                                                         |         |
| A   | T5 5<br>9 |          | Deleted HiPerClockS references.<br>Crystal Characteristics Table - added note.<br>Deleted application note, <i>LVCMOS to XTAL Interface</i> .<br>Deleted quantity from tape and reel | 11/2/12 |
|     |           |          |                                                                                                                                                                                      |         |

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